Preferred Devices

SWITCHMODE [™] **Power Rectifiers**

This series are state-of-the-art devices designed for use in switching power supplies, inverters and as free wheeling diodes.

Features

- Ultrafast 25, 50 and 75 Nanosecond Recovery Time
- 175°C Operating Junction Temperature
- Popular TO-220 Package
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Low Forward Voltage
- Low Leakage Current
- High Temperature Glass Passivated Junction
- Reverse Voltage to 600 V
- Pb-Free Packages are Available*

Mechanical Characteristics:

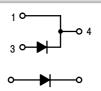
- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max for 10 Seconds

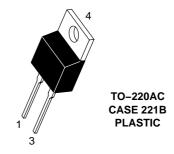


ON Semiconductor®

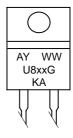
http://onsemi.com

ULTRAFAST RECTIFIERS 8.0 AMPERES, 50–600 VOLTS





MARKING DIAGRAM



A = Assembly Location

Y = Year WW = Work Week U8xx = Device Code

xx = 05, 10, 15, 20, 40 or 60

G = Pb-Free Package KA = Diode Polarity

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS

		MUR						
Rating	Symbol	805	810	815	820	840	860	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	50	100	150	200	400	600	V
Average Rectified Forward Current Total Device, (Rated V_R), $T_C = 150^{\circ}C$	I _{F(AV)}			8	.0			А
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz), T _C = 150°C	I _{FM}			1	6			А
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		100					А	
Operating Junction Temperature and Storage Temperature Range	T _J , T _{stg}	T _J , T _{stg} -65 to +175			°C			

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

		MUR						
Rating	Symbol	805	810	815	820	840	860	Unit
Maximum Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	3.0 2.0		.0	°C/W			

ELECTRICAL CHARACTERISTICS

		MUR						
Rating	Symbol	805	810	815	820	840	860	Unit
Maximum Instantaneous Forward Voltage (Note 1) ($i_F = 8.0 \text{ A}, T_C = 150^{\circ}\text{C}$) ($i_F = 8.0 \text{ A}, T_C = 25^{\circ}\text{C}$)	V _F		0.8 0.9	395 975		1.00 1.30	1.20 1.50	V
Maximum Instantaneous Reverse Current (Note 1) (Rated DC Voltage, T _J = 150°C) (Rated DC Voltage, T _J = 25°C)	i _R	250 5.0		500 10		μА		
Maximum Reverse Recovery Time $ \begin{array}{l} (I_F=1.0 \text{ A, di/dt}=50 \text{ A/}\mu\text{s}) \\ (I_F=0.5 \text{ A, i}_R=1.0 \text{ A, } I_{REC}=0.25 \text{ A}) \end{array} $	t _{rr}	35 25		60 50		ns		

^{1.} Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%.

MUR805, MUR810, MUR815, MUR820

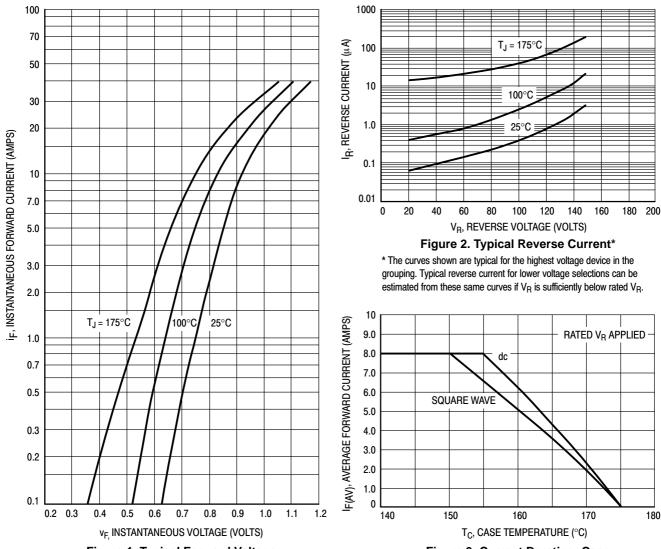


Figure 1. Typical Forward Voltage



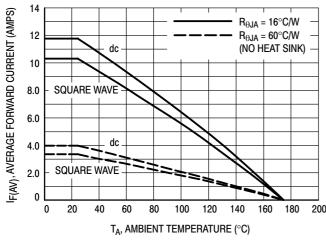


Figure 4. Current Derating, Ambient

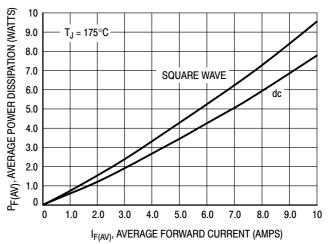


Figure 5. Power Dissipation

MUR840

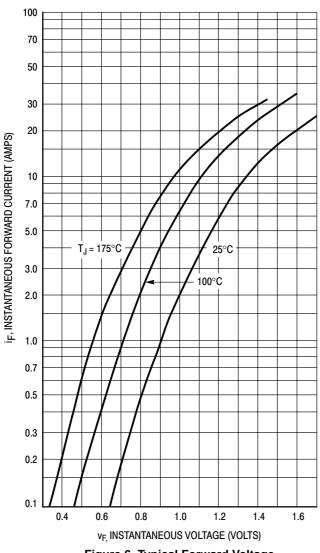


Figure 6. Typical Forward Voltage

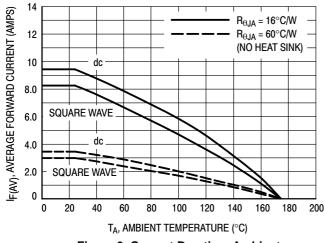


Figure 9. Current Derating, Ambient

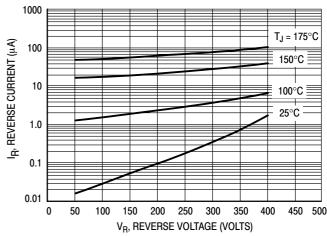


Figure 7. Typical Reverse Current*

 * The curves shown are typical for the highest voltage device in the grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if V_B is sufficiently below rated V_B .

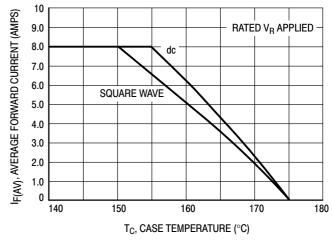


Figure 8. Current Derating, Case

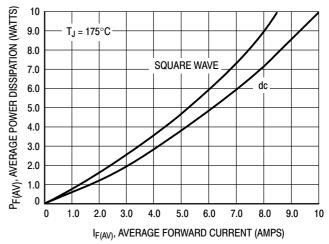
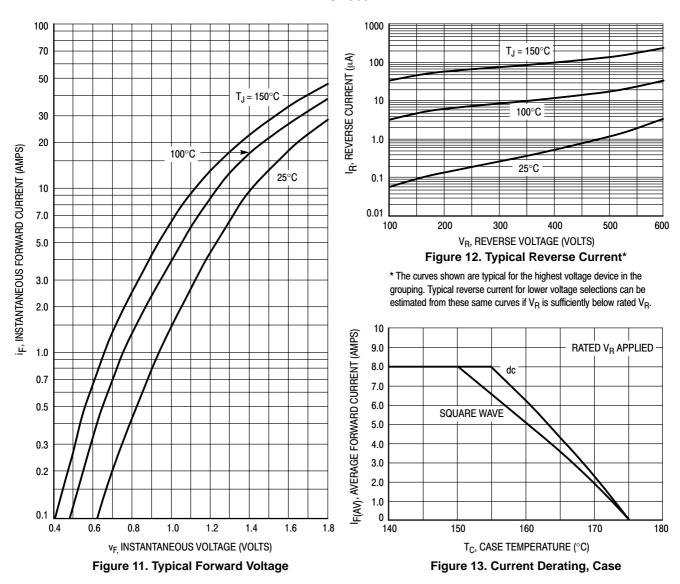


Figure 10. Power Dissipation

MUR860



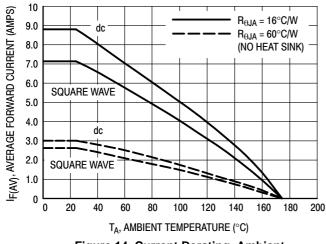


Figure 14. Current Derating, Ambient

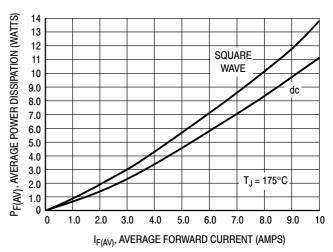


Figure 15. Power Dissipation

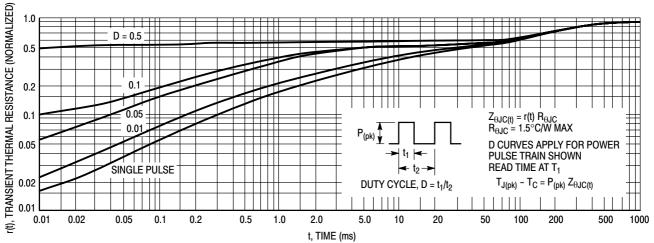


Figure 16. Thermal Response

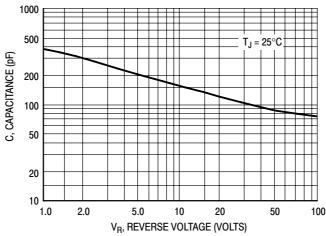


Figure 17. Typical Capacitance

ORDERING INFORMATION

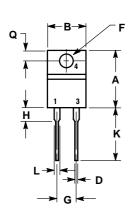
Device	Package	Shipping [†]
MUR805	TO-220	
MUR805G	TO-220 (Pb-Free)	
MUR810	TO-220	
MUR810G	TO-220 (Pb-Free)	
MUR815	TO-220	
MUR815G	TO-220 (Pb-Free)	50 Haira / Dail
MUR820	TO-220	50 Units / Rail
MUR820G	TO-220 (Pb-Free)	
MUR840	TO-220	
MUR840G	TO-220 (Pb-Free)	
MUR860 MUR860G	TO-220	
	TO-220 (Pb-Free)	

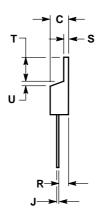
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TO-220 TWO-LEAD

CASE 221B-04 ISSUE D





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
 Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

	INC	HES	MILLIMETER			
DIM	MIN	MAX	MIN	MAX		
Α	0.595	0.620	15.11	15.75		
В	0.380	0.405	9.65	10.29		
С	0.160	0.190	4.06	4.82		
D	0.025	0.035	0.64	0.89		
F	0.142	0.147	3.61	3.73		
G	0.190	0.210	4.83	5.33		
Н	0.110	0.130	2.79	3.30		
J	0.018	0.025	0.46	0.64		
K	0.500	0.562	12.70	14.27		
L	0.045	0.060	1.14	1.52		
Q	0.100	0.120	2.54	3.04		
R	0.080	0.110	2.04	2.79		
S	0.045	0.055	1.14	1.39		
Т	0.235	0.255	5.97	6.48		
U	0.000	0.050	0.000	1.27		

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